

Resonac Photonics Corporation

Marketing Department
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KM89528NF

1. Material GaAlAs

2. Electrode N (cathode) side : Au

P (anode) side : Au

3. Electrode pattern Fig.1

4. Chip size 0.265 mm × 0.265 mm × 0.210 mm (Fig.1)

5. Emission area 0.230mm X 0.230mm (Fig.1)

6. Electro-Optical characteristics (Ta = 25°C)

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Parameters	Symbol	Condition	Min	Тур	Max	Unit
Power	Po	IF=20mA	1.6	3.6	-	mW
Forward Voltage	VF	IF=20mA	-	1.33	1.39	V
Reverse Current	IR	VR=3V	-	-	10	uA
Peak Wavelength	λр	IF=20mA	885	895	905	nm
Spectral Radiation	Δλ(*)	IF=20mA	-	50	-	nm
Bandwidth						

- * (*) mark is reference data
- * Power Measurement at Resonac Photonics.
- 7. Recommended bonding method Ultra-sonic method or a combination of ultra-sonic and thermo-compression methods.

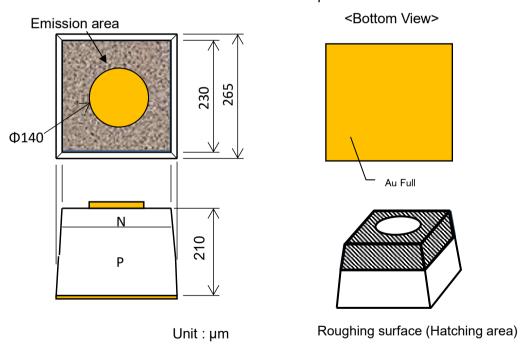


Fig.1: Chip size and Emission area and Electrode pattern

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However, no representations, guaranties or warranties of any kind are made as to accuracy and suitability of the Product for particular applications or the results of its use.

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